

LMH9226 Single-Ended to Differential 2.3-GHz to 2.9-GHz RF Amplifier With Balun

1 Features

- Single-channel, single-ended input to differential output RF gain block amplifier
- Supports 2.6-GHz center frequency with 400-MHz, 1-dB bandwidth
- 17-dB typical gain across the 1-dB bandwidth into $Z_{LOAD} = 50\ \Omega$
- Noise figure < 3 dB in 1-dB bandwidth
- 35-dBm OIP3 at 2-dBm two-tone output power into $Z_{LOAD} = 50\ \Omega$
- 17.5-dBm output P1dB into $Z_{LOAD} = 50\ \Omega$
- 275-mW power consumption on 3.3-V single supply
- Up to $T_A = 105^\circ\text{C}$ operating temperature

2 Applications

- 5G m-MIMO base stations
- [Active antenna systems, m-MIMO \(AAS\)](#)
- [Small cell base stations](#)
- TDD/FDD cellular base station
- Wireless infrastructure
- Low-cost radios
- Single-ended to differential conversion
- Balun alternatives
- RF gain blocks
- Differential driver for GPS ADCs

3 Description

The LMH9226 is high-performance, single-channel, single-ended, 50- Ω input to differential 50- Ω or 100- Ω output RF gain block amplifier supporting a 2.3-GHz to 2.9-GHz frequency band. The device is well suited to meet requirements for 5G m-MIMO or small cell base station applications. The device integrates the functionality of a single-ended input and output RF gain block followed by a passive balun, where the device is mainly used in the final stage of a receiver signal chain to drive the full-scale voltage of an analog-to-differential converter (ADC) differential input.

The LMH9226 provides 17-dB typical gain with excellent linearity performance of 35-dBm output IP3 at 2.6 GHz, and maintains less than a 3-dB noise figure across the entire 1-dB bandwidth of 400 MHz. The device is internally matched for a 50- Ω impedance at the single-ended input. The differential output can easily interface to a 50- Ω impedance without any external matching circuitry. For 100- Ω impedance matching, an external matching circuitry is required that typically results in a 0.3-dB gain loss at 2.6 GHz.

Operating on a single 3.3-V supply, the device consumes approximately 275 mW of stand-by power, making the device suitable for high-density, 5G, massive multiple-input and multiple-output (MIMO) applications. Also, the device is available in a space-saving, 2-mm $\times$ 2-mm, 12-pin WQFN package. The device is rated for an operating temperature of up to 105°C to provide a robust system design. A 1.8-V JEDEC compliant power-down pin is available for fast power-down and power-up of the device that is suitable for time division duplex (TDD) systems.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LMH9226	WQFN (12)	2.00 mm $\times$ 2.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

LMH9226: 2.3-GHz to 2.9-GHz Single-Ended Input to Differential Output RF Gain Block Amplifier

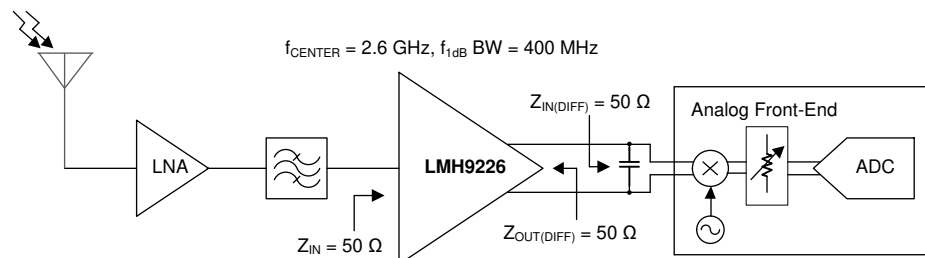


Table of Contents

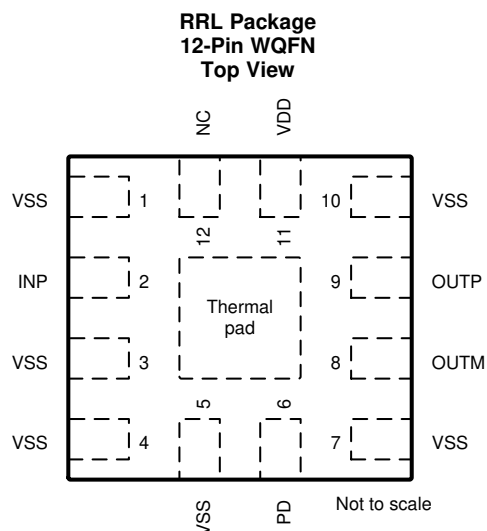
1 Features	1	7.4 Device Functional Modes.....	10
2 Applications	1	8 Application and Implementation	10
3 Description	1	8.1 Application Information.....	10
4 Revision History	2	8.2 Typical Application	10
5 Pin Configuration and Functions	3	9 Power Supply Recommendations	13
6 Specifications	4	10 Layout	14
6.1 Absolute Maximum Ratings	4	10.1 Layout Guidelines	14
6.2 ESD Ratings.....	4	10.2 Layout Example	14
6.3 Recommended Operating Conditions.....	4	11 Device and Documentation Support	15
6.4 Thermal Information	4	11.1 Documentation Support	15
6.5 Electrical Characteristics.....	5	11.2 Receiving Notification of Documentation Updates	15
6.6 Typical Characteristics	6	11.3 Community Resources.....	15
7 Detailed Description	9	11.4 Trademarks	15
7.1 Overview	9	11.5 Electrostatic Discharge Caution.....	15
7.2 Functional Block Diagram	9	11.6 Glossary	15
7.3 Feature Description.....	9	12 Mechanical, Packaging, and Orderable Information	15

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
December 2019	*	Initial release.

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	VSS	Power	Analog ground
2	INP	Input	RF single-ended input into amplifier
3	VSS	Power	Analog ground
4	VSS	Power	Analog ground
5	VSS	Power	Analog ground
6	PD	Input	Power-down connection. PD = 0 V, normal operation; PD = 1.8 V, power off mode.
7	VSS	Power	Analog ground
8	OUTM	Output	RF single-ended output negative
9	OUTP	Output	RF single-ended output positive
10	VSS	Power	Analog ground
11	VDD	Power	Positive supply voltage (3.3 V)
12	NC	—	Do not connect this pin
Thermal Pad		—	Connect the thermal pad to ground (VSS).

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply voltage	VDD	−0.3	3.6	V
RF pins	INP, OUTP, OUTM	−0.3	VDD	V
Continuous wave (CW) input	$f_{in} = 2.6$ GHz at INP		25	dBm
Digital input pin	PD	−0.3	VDD	V
Junction temperature	T_J		150	°C
Storage temperature	T_{stg}	−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, allpins ⁽¹⁾	±1000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
VDD	Supply voltage	3.15	3.3	3.45	V
T_A	Ambient temperature	−40		105	°C
T_J	Junction temperature	−40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		LMH9226	UNIT
		RRL PKG	
		12-PIN WQFN	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	74.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	72.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	3.2	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	37.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	14.2	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

$T_A = +25^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$, center frequency (f_{in}) = 2.6 GHz, single-ended input impedance (Z_{in}) = 50 Ω , differential output impedance (Z_{LOAD}) = 50 Ω , $P_{OUT(TOTAL)} = 8\text{ dBm}$ into $Z_{LOAD} = 50\text{ }\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
RF PERFORMANCE						
f_{RF}	RF frequency range		2300		2900	MHz
BW_{1dB}	1-dB bandwidth	Center Frequency (f_{in}) = 2.6 GHz		400		MHz
S21	Gain	$f_{in} = 2.6\text{ GHz}$		17		dB
NF	Noise figure	$f_{in} = 2.6\text{ GHz}$, $R_S = 50\text{ }\Omega$		3		dB
OIP1	Output P1dB	$f_{in} = 2.6\text{ GHz}$, $R_{LOAD} = 50\text{ }\Omega$		17.5		dBm
OIP3	Output IP3	$f_{in} = 2.6\text{ GHz} \pm 10\text{ MHz spacing}$, $P_{OUT/TONE} = 2\text{ dBm}$		35		dBm
	Differential output gain imbalance ⁽¹⁾			0.5		dB
	Differential output phase imbalance ⁽¹⁾			4		degree
S11	Input return loss	$f_{in} = 2.6\text{ GHz}$, $BW = 400\text{ MHz}$		-11		dB
Z_{in}	Single ended input reference impedance			50		Ω
S22	Differential output return loss	$f_{in} = 2.6\text{ GHz}$, $BW = 400\text{ MHz}$		-12		dB
Z_{LOAD}	Differential output reference impedance			50		Ω
S12	Reverse isolation	$f_{in} = 2.6\text{ GHz}$		-35		dB
CMRR	Common-mode rejection ratio ⁽²⁾			27		dB
SWITCHING AND DIGITAL INPUT CHARACTERISTICS						
t_{ON}	Turn-on time	PD pin = 1.8 V to 0 V, $f_{in} = 2.6\text{ GHz}$		0.5		μs
t_{OFF}	Turn-off time	PD pin = 0 V to 1.8 V, $f_{in} = 2.6\text{ GHz}$		0.2		μs
V_{IH}	High-level input voltage ⁽³⁾	At the PD pin	1.4			V
V_{IL}	Low-level input voltage ⁽³⁾	At the PD pin			0.5	V
I_{IH}	High-level input current ⁽³⁾	At the PD pin		28	60	μA
I_{IL}	Low-level input current ⁽³⁾	At the PD pin		10	30	μA
DC CURRENT AND POWER CONSUMPTION						
I_{VDD_ON}	Supply current ⁽³⁾	PD pin = 0 V		84	100	mA
I_{VDD_PD}	Power-down current ⁽³⁾	PD pin = 1.8 V			10	mA
P_{dis}	Power dissipation	$V_{DD} = 3.3\text{ V}$		275		mW

(1) Measured at $f_{in} = 2.6\text{ GHz}$, over the BW_{1dB}

(2) CMRR is calculated using $(S21-S31)/(S21+S31)$ for receive (1 is input port, 2 and 3 are differential output ports)

(3) 100% tested at $T_A = 25^\circ\text{C}$

6.6 Typical Characteristics

at $T_A = 25^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = $50\ \Omega$, differential output impedance (Z_{LOAD}) = $50\ \Omega$, and $P_{OUT(TOTAL)} = 8\text{ dBm}$ into $Z_{LOAD} = 50\ \Omega$ (unless otherwise noted)

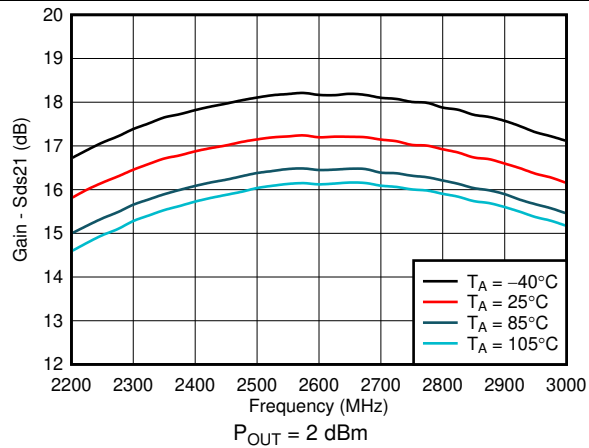


Figure 1. Gain vs Frequency and Temperature

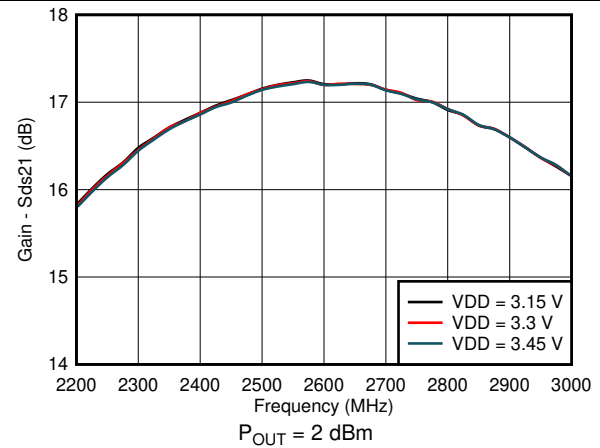


Figure 2. Gain vs Frequency and Supply Voltage

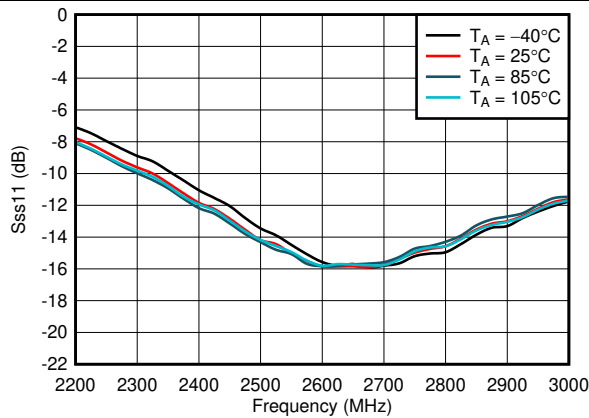


Figure 3. Input Return Loss vs Frequency

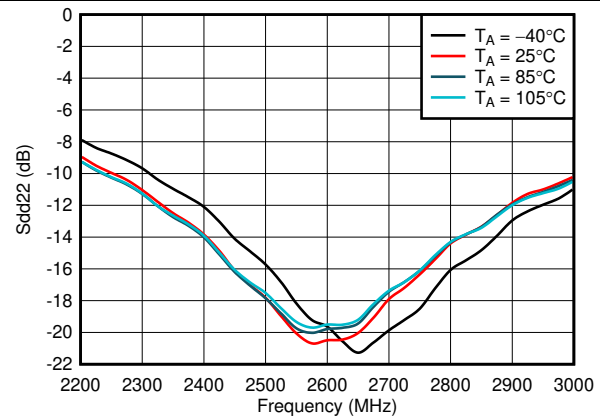


Figure 4. Output Return Loss vs Frequency

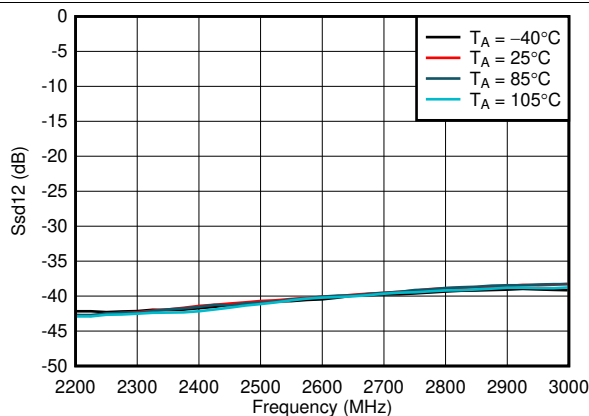


Figure 5. Reverse Isolation vs Frequency

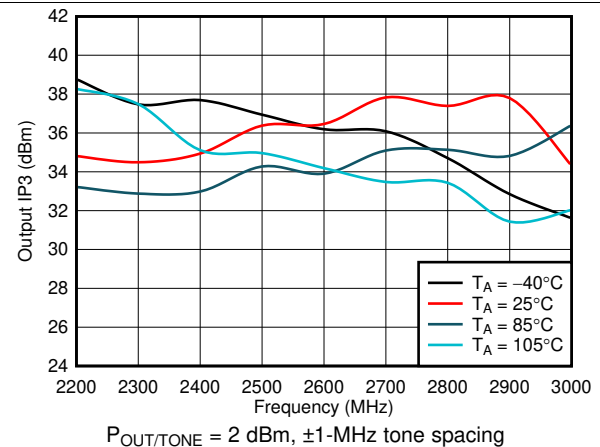


Figure 6. Output IP3 vs Frequency and Temperature

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = $50\ \Omega$, differential output impedance (Z_{LOAD}) = $50\ \Omega$, and $P_{OUT(TOTAL)} = 8\text{ dBm}$ into $Z_{LOAD} = 50\ \Omega$ (unless otherwise noted)

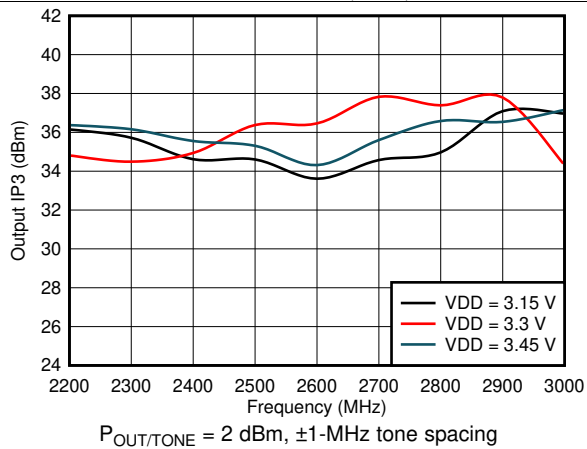


Figure 7. Output IP3 vs Frequency and Supply Voltage

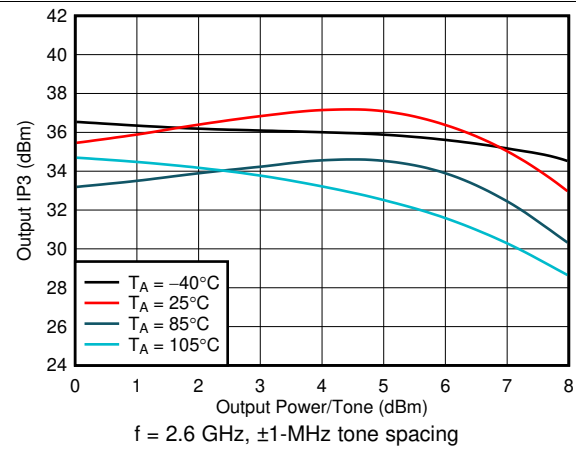


Figure 8. Output IP3 vs Output Power per Tone

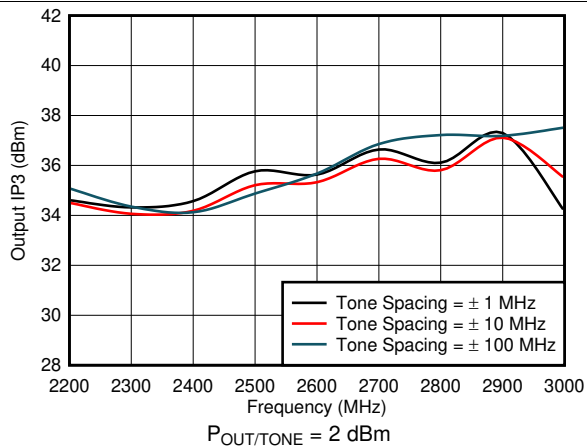


Figure 9. Output IP3 vs Frequency and Tone Spacing

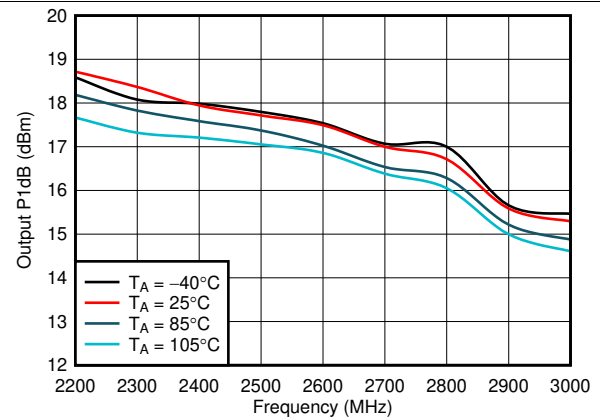


Figure 10. Output P1dB vs Frequency and Temperature

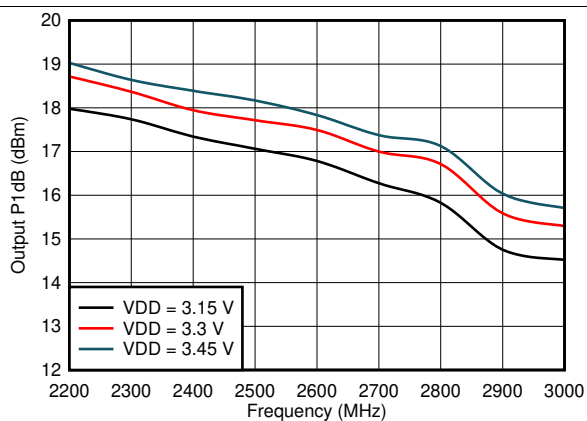


Figure 11. Output P1dB vs Frequency and Supply Voltage

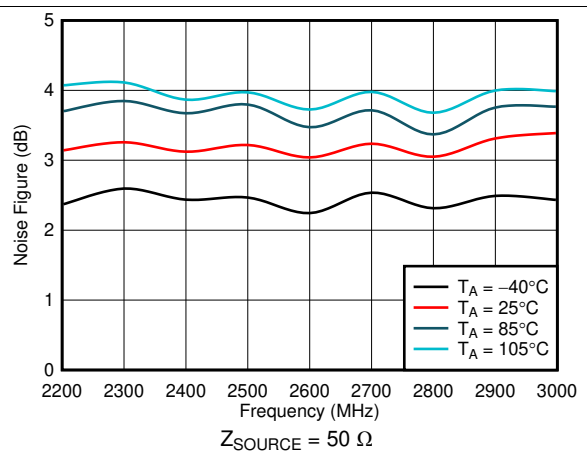


Figure 12. Noise Figure vs Frequency and Temperature

Typical Characteristics (continued)

at $T_A = 25^\circ\text{C}$, $V_{DD} = 3.3\text{ V}$, center frequency (f_{IN}) = 2.6 GHz, single-ended input impedance (Z_{IN}) = $50\ \Omega$, differential output impedance (Z_{LOAD}) = $50\ \Omega$, and $P_{OUT(TOTAL)} = 8\text{ dBm}$ into $Z_{LOAD} = 50\ \Omega$ (unless otherwise noted)

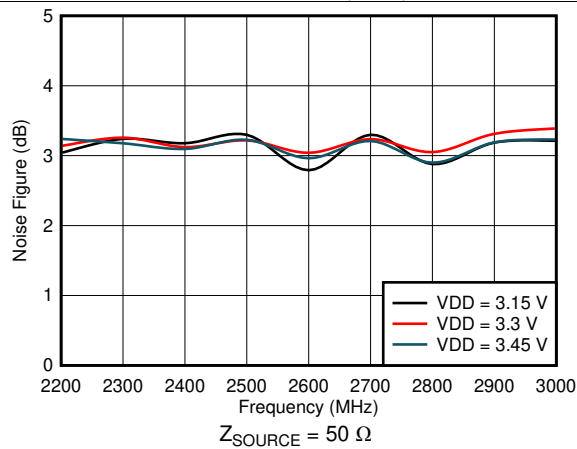


Figure 13. Noise Figure vs Frequency and Supply Voltage

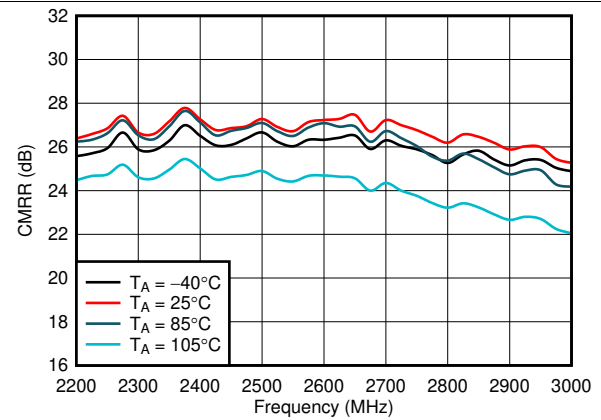


Figure 14. CMRR vs Frequency

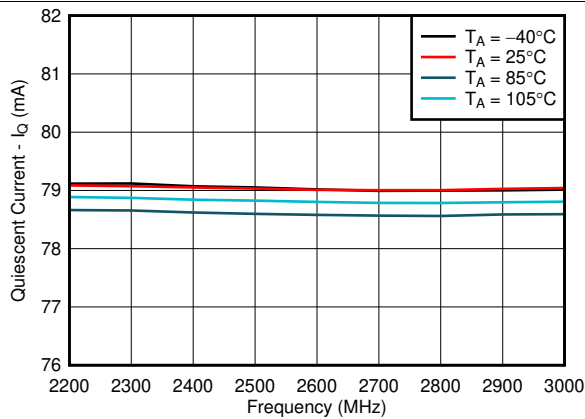


Figure 15. Quiescent Current vs Frequency and Temperature

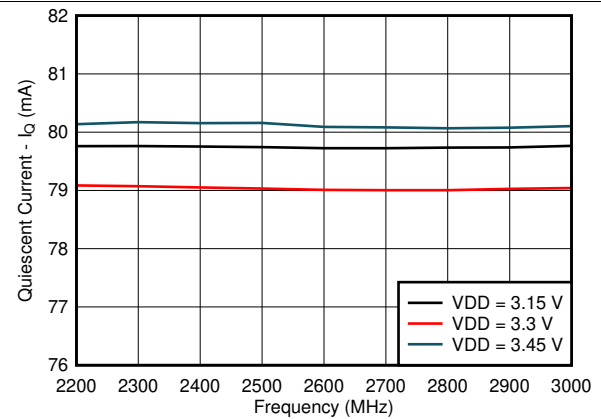


Figure 16. Quiescent Current vs Frequency and Supply Voltage

7 Detailed Description

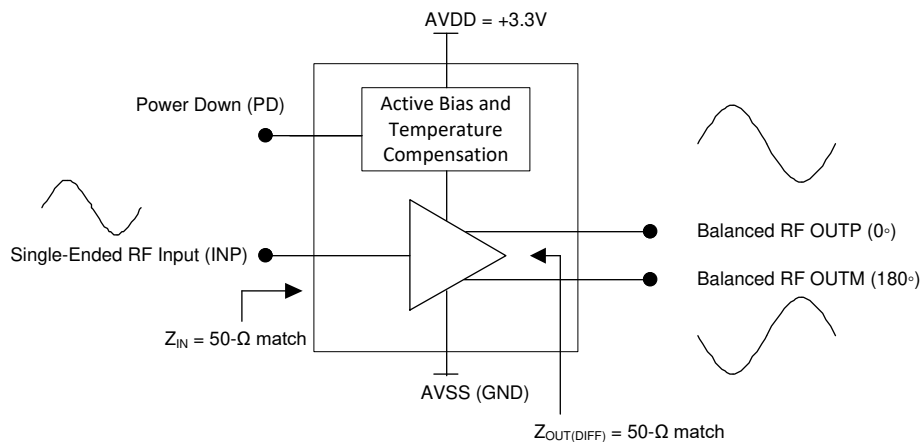
7.1 Overview

The LMH9226 is single-ended, 50-Ω input to differential 50-Ω or 100-Ω output RF gain block amplifier used in 2.3-GHz to 2.9-GHz, frequency-band, 5G, m-MIMO TDD receiver applications. The device provides a 17-dB fixed power gain with excellent linearity and noise performance across 400 MHz of the 1-dB bandwidth at the 2.6-GHz center frequency. The device is internally matched for a 50-Ω input impedance at 2.6 GHz. The device differential output can be matched to the 50-Ω impedance without external matching circuitry, or to the 100-Ω impedance with external matching circuitry (see the [Application and Implementation](#) section for details). The device is typically used in the final stage of a receive signal chain to drive the differential input of an analog-to-differential converter (ADC), while providing additional gain to a low-noise amplifier (LNA) to increase dynamic range and the required single-ended to differential conversion.

The LMH9226 has an on-chip active bias circuitry to maintain device performance over a wide temperature and supply voltage range. The included power-down function allows the amplifier to shut down and save power when the amplifier is not needed. Fast shut-down and start-up enable the amplifier to be used in a host of time division duplex (TDD) applications.

Operating on a single 3.3-V supply and consuming 84 mA of typical supply current, the device is available in a 2-mm × 2-mm, 12-pin WQFN package.

7.2 Functional Block Diagram



7.3 Feature Description

As shown in [Figure 17](#), the LMH9226 integrates the functionality of a single-ended RF amplifier and passive balun in a traditional receive application, achieving a small form factor with good linearity and noise performance. The active balun implementation, along with a higher operating temperature of 105°C, allows for a more robust receiver system implementation compared to a passive balun that is prone to reliability failures at high temperatures. The high-temperature operation is achieved by the on-chip, active bias circuitry that maintains device performance over a wide temperature and supply voltage range.

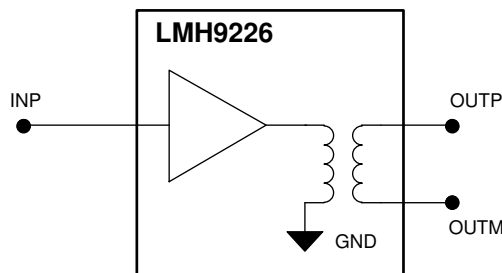


Figure 17. Single-Ended Input to Differential Output, Active Balun Implementation

7.4 Device Functional Modes

The LMH9226 features a PD pin that must be connected to GND for normal operation. For power-down mode, connect the PD pin to a logic high voltage of 1.8 V.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The LMH9226 is a single-ended, 50-Ω input to differential 50-Ω or 100-Ω output RF gain block amplifier, used in the receive path of a 2.6-GHz center frequency, 5G, TDD m-MIMO or small cell base station. The device replaces the traditional single-ended RF amplifier and passive balun offering a smaller footprint solution to the customer. TI recommends following good RF layout and grounding techniques to maximize the device performance.

8.2 Typical Application

The LMH9226 is typically used in a four transmit and four receive (4T/4R) array of active antenna system for 5G, TDD, wireless base station applications. Such a system is shown in Figure 18, where the LMH9226 is used in the receive path as the final stage differential driver to an ADC input. TI typically recommends reducing the trace distance between the LMH9226 output and the ADC input to minimize amplitude and phase imbalance during the single-to-differential conversion.

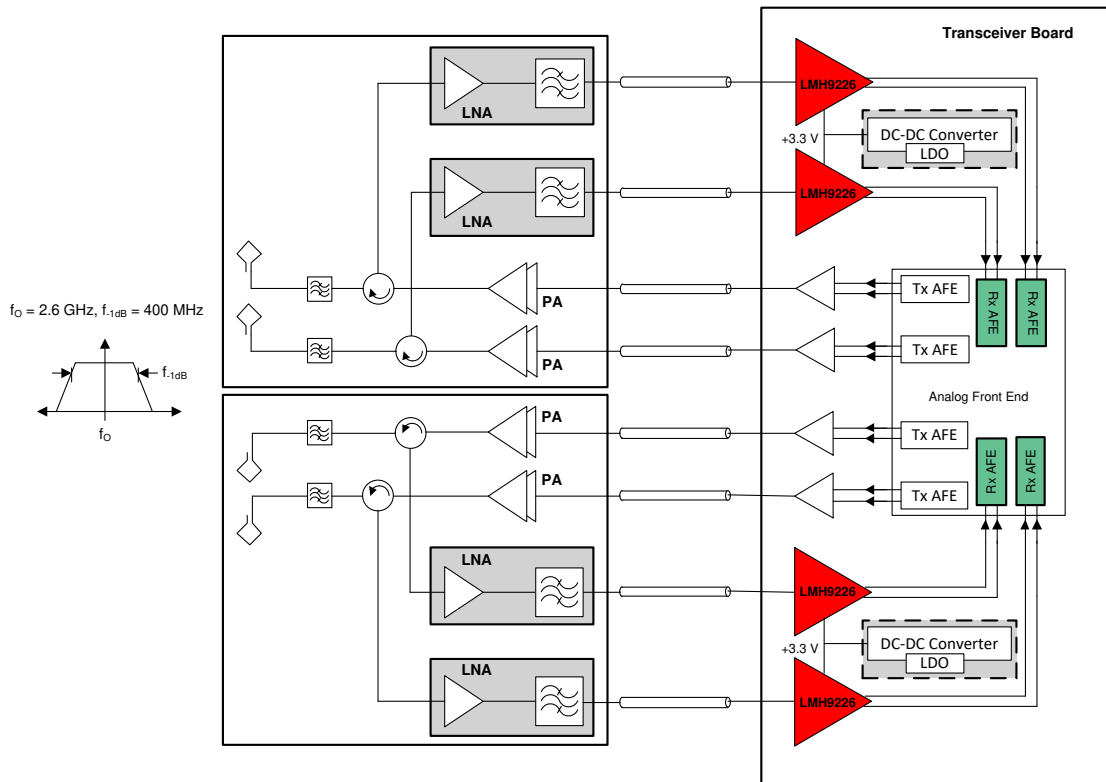


Figure 18. LMH9226 in a 4T/4R 5G Active Antenna System

Typical Application (continued)

The 4T/4R system is easily scaled to 16T/16R, 64T/64R, or higher antenna arrays that result in proportional scaling of the overall system power dissipation. As a result of the proportional scaling factor for multiple channels in a system, the individual device power consumption must be reduced to dissipate less overall heat in the system. Operating on a single 3.3-V supply, the LMH9226 consumes only 275 mW and therefore provides power saving to the customer. Multiple LMH9226 devices can be powered from a single DC/DC converter or a low-dropout regulator (LDO) operating on a 3.3-V supply. A DC/DC converter provides the most power efficient way of generating the 3.3-V supply. However, care must be taken when using the DC/DC converter to minimize the switching noise using inductor chokes and adequate isolation must be provided between the analog and digital supplies.

8.2.1 Design Requirements

Table 1 shows example design requirements for an RF amplifier in a typical 5G, active antenna TDD system. The LMH9226 meets these requirements.

Table 1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUE
Frequency range and 1-dB BW	2300 MHz to 2900 MHz with 400 MHz of 1-dB BW
Configuration	Single-ended 50-Ω input to differential 50-Ω output
Power gain	> 15 dB
Output IP3 at $P_{OUT/TONE} = 2$ dBm	> 32 dBm
Noise figure at $Z_{in} = 50\ \Omega$	< 4 dB
Output P1dB	< 17 dBm
Power consumption	< 350 mW
Turn-on time	< 1 μ s
Package size	2 mm × 2 mm ²

8.2.2 Detailed Design Procedure

The LMH9226 is a single-to-differential RF gain block amplifier for a 2.6-GHz center frequency application with 400 MHz of the 1-dB bandwidth. Figure 19 shows a single receive channel consisting of a low-noise amplifier (LNA) that sits close to the antenna and drives the signal into a single-ended, 50-Ω coaxial cable that then connects to a transceiver board. The LMH9226 that sits at the transceiver board input converts this single-ended signal received from the coax cable into a differential signal, thereby offering low noise and distortion performance while interfacing with the receiver analog front-end (AFE). The LMH9226 input impedance must be matched to 50 Ω to prevent any signal reflections resulting from the coax cable. The device differential output interfaces directly with the differential input of an AFE. The output matching is optimized for a 50-Ω output at the 2.6-GHz center frequency with 400 MHz of the 1-dB bandwidth. The AFE input impedance must be matched to 50 Ω at 2.6 GHz as well to prevent any ripple in the frequency response.

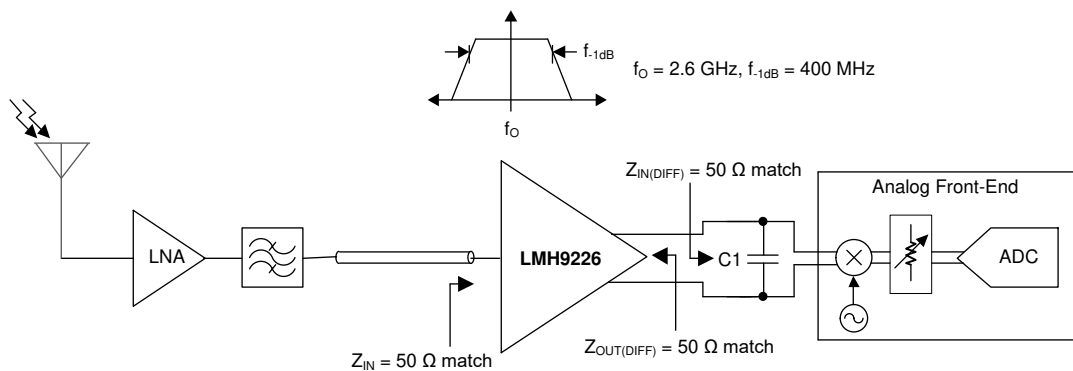


Figure 19. LMH9226 in a Receive Application Driving an AFE ($Z_{OUT(DIFF)} = 50\ \Omega$)

For interfacing with a 100- Ω differential input AFE, as shown in Figure 20, an external matching circuitry is needed close to the LMH9226 output. Table 2 lists example recommended component values when transforming the LMH9226 output impedance from 50 Ω to 100 Ω . The component values must be tweaked on the board, depending on the trace length between the matching circuitry and the AFE input to maintain 400 MHz of the 1-dB BW at the 2.6-GHz center frequency. LC component values must be selected with $Q(\min) > 30$ that have a self resonant frequency (SRF) sufficiently higher than the desired frequency of operation. Figure 21 and Figure 22 provide a comparison of device performance when interfacing with a 50- Ω output matching as compared to a 100- Ω output matching. As depicted in Figure 21, the forward path gain (S_{DS21}) is slightly lower for the 100- Ω differential output impedance because of the extra loss in the external matching circuitry.

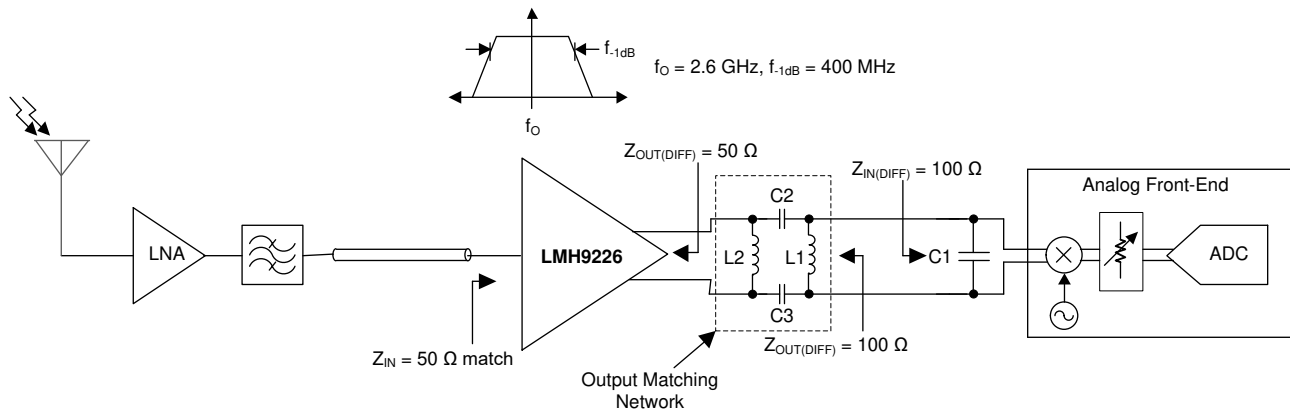


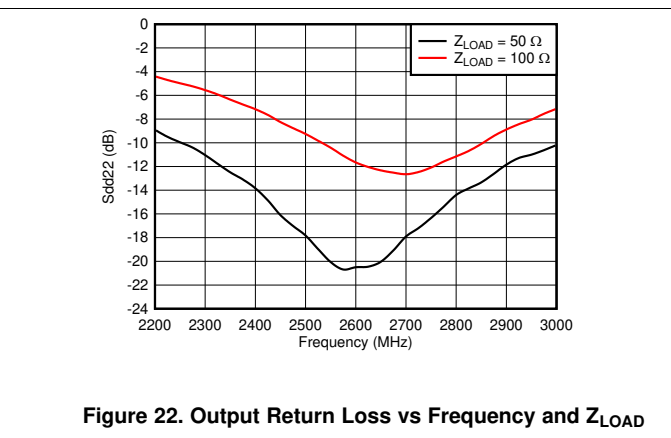
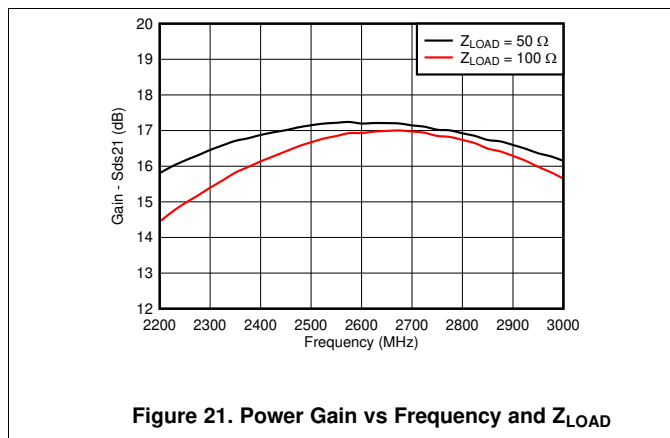
Figure 20. LMH9226 in a Receive Application Driving an AFE ($Z_{OUT(DIFF)} = 100 \Omega$)

Table 2. Output Matching Network Component Values

COMPONENT	VALUE
C2, C3	2.2 pF
L1	6.2 nH
L2	Do not install (DNI)

Following the recommended RF layout with good quality RF components and local DC bypass capacitors ensures optimal performance is achieved. TI provides various support materials including S-parameter and ADS models to allow the design to be optimized to the application-specific performance needs.

8.2.3 Application Curves



9 Power Supply Recommendations

The LMH9226 operates on a common nominal 3.3-V supply voltage. The supply voltage is recommended to be isolated through the decoupling capacitors placed close to the device. Select capacitors with a self-resonant frequency near the application frequency. When multiple capacitors are used in parallel to create a broadband decoupling network, place the capacitor with the higher self-resonant frequency closer to the device.

The LMH9226 can be powered from a DC/DC converter or an LDO operating on a 3.3-V supply. A DC/DC converter provides the most power efficient way of generating the 3.3-V supply. However, care must be taken when using the DC/DC converter to minimize the switching noise from inductor chokes and adequate isolation must be provided between the analog and digital supplies.

10 Layout

10.1 Layout Guidelines

When dealing with an RF amplifier with relatively high gain and a center frequency of 2.6 GHz, certain board layout precautions must be taken to ensure stability and optimum performance. TI recommends that the LMH9226 board be multi-layered to improve thermal performance, grounding, and power-supply decoupling. [Figure 23](#) shows a good layout example. In [Figure 23](#), only the top signal layer and its adjacent ground reference plane are shown.

- Excellent electrical connection from the thermal pad to the board ground is essential. Use the recommended footprint, solder the pad to the board, and do not include a solder mask under the pad.
- Connect the pad ground to the device terminal ground on the top board layer.
- Verify that the return DC and RF current path have a low impedance ground plane directly under the package and that the RF signal traces into and out of the amplifier.
- Ensure that ground planes on the top and any internal layers are well stitched with vias.
- Do not route RF signal lines over breaks in the reference ground plane.
- Avoid routing clocks and digital control lines near RF signal lines.
- Do not route RF or DC signal lines over noisy power planes. Ground is the best reference, although clean power planes can serve where necessary.
- Place supply decoupling close to the device.
- The differential output traces must be symmetrical in order to achieve the best linearity performance.

A board layout software package can simplify the trace thickness design to maintain impedances for controlled impedance signals. To isolate the affect of board parasitic on frequency response, TI recommends placing the external output matching resistors close to the amplifier output pins. See the [LMH9226 Evaluation Module user guide](#) for more details on board layout and design.

10.2 Layout Example

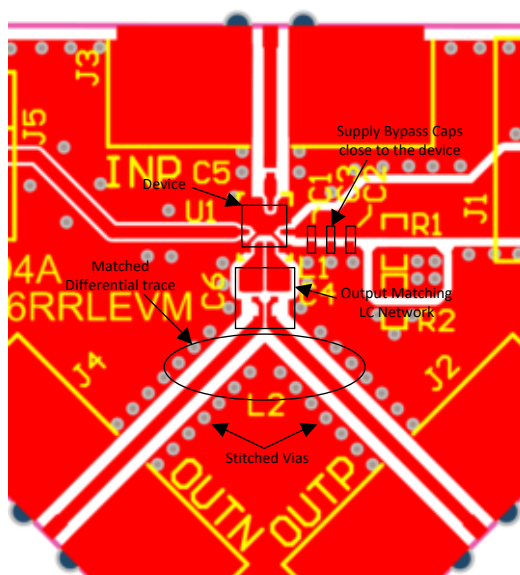


Figure 23. Supply Bypass and Output Matching

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

Texas Instruments, [LMH9226 Evaluation Module user guide](#)

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Community Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

11.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LMH9226IRRLR	Active	Production	WQFN (RRL) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 105	22GO
LMH9226IRRLR.B	Active	Production	WQFN (RRL) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 105	22GO

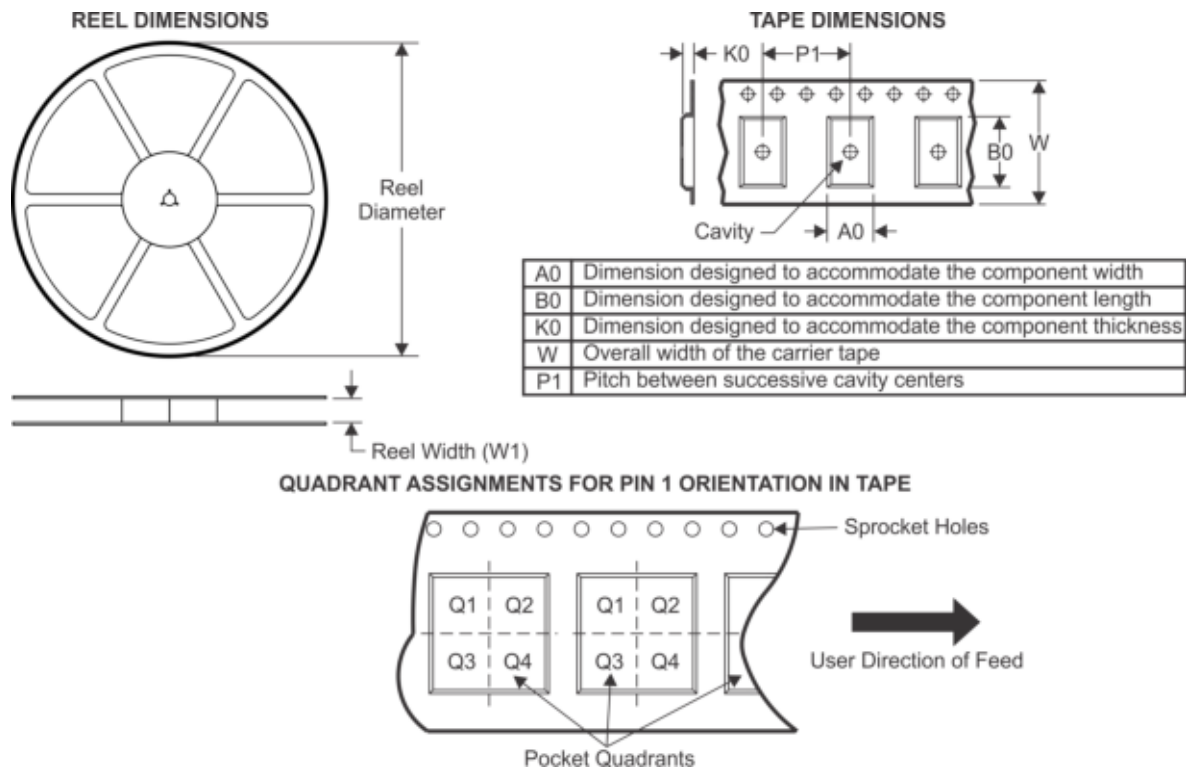
- ⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).
- ⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- ⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- ⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- ⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- ⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

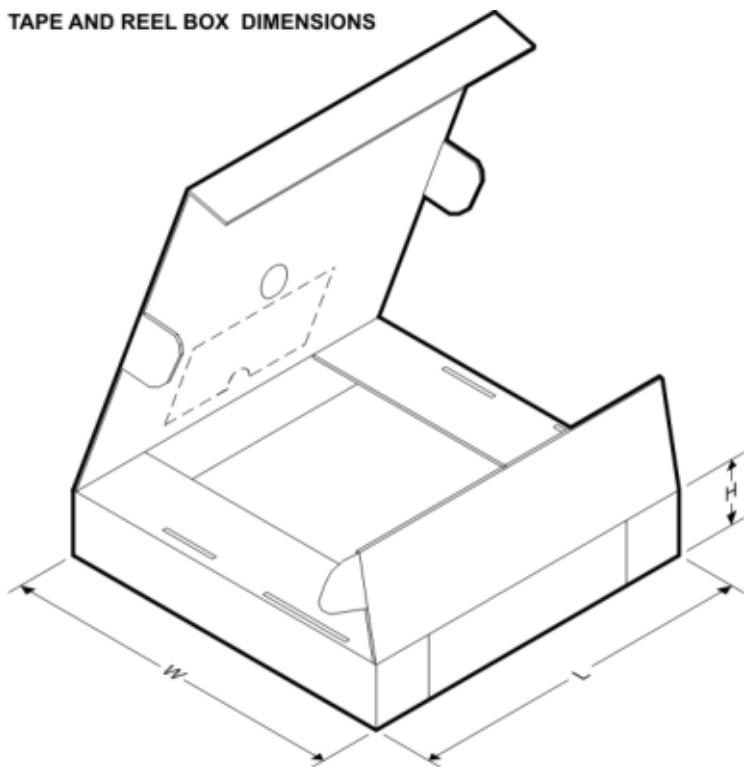
TAPE AND REEL INFORMATION



*All dimensions are nominal

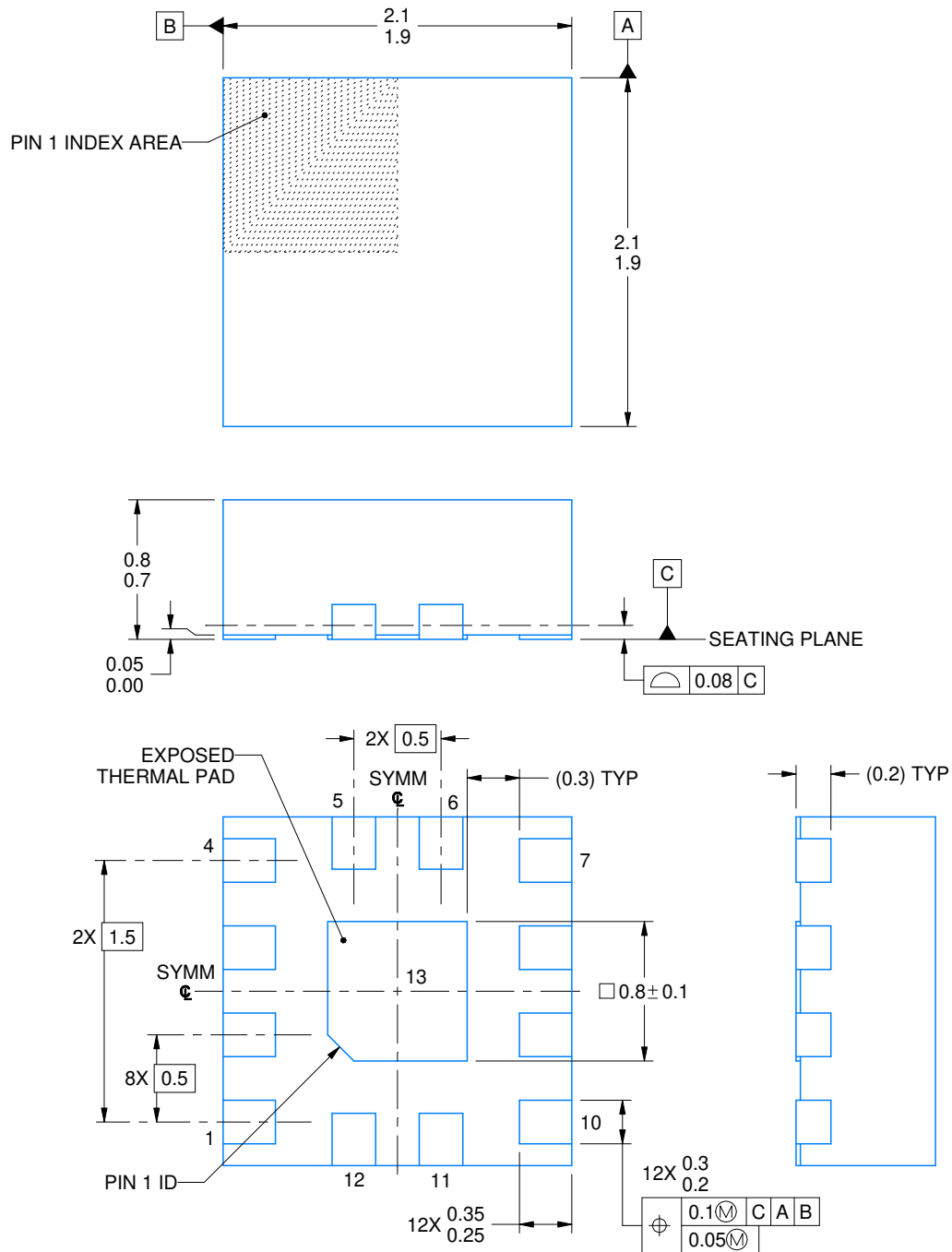
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMH9226IRRLR	WQFN	RRL	12	3000	180.0	8.4	2.2	2.2	1.2	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMH9226IRRLR	WQFN	RRL	12	3000	213.0	191.0	35.0



4224942/A 04/2019

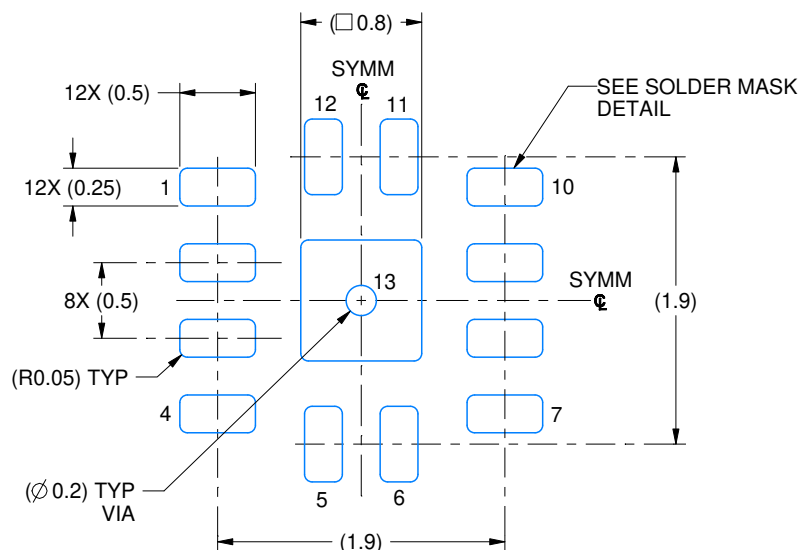
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

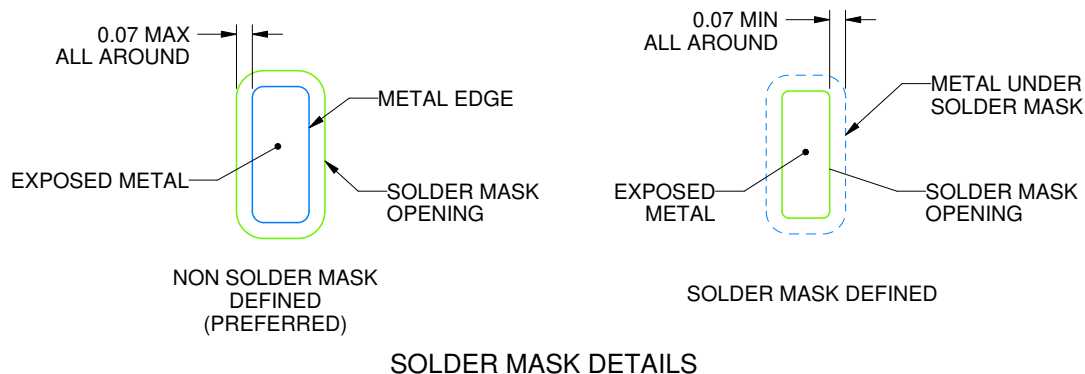
RRL0012A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



4224942/A 04/2019

NOTES: (continued)

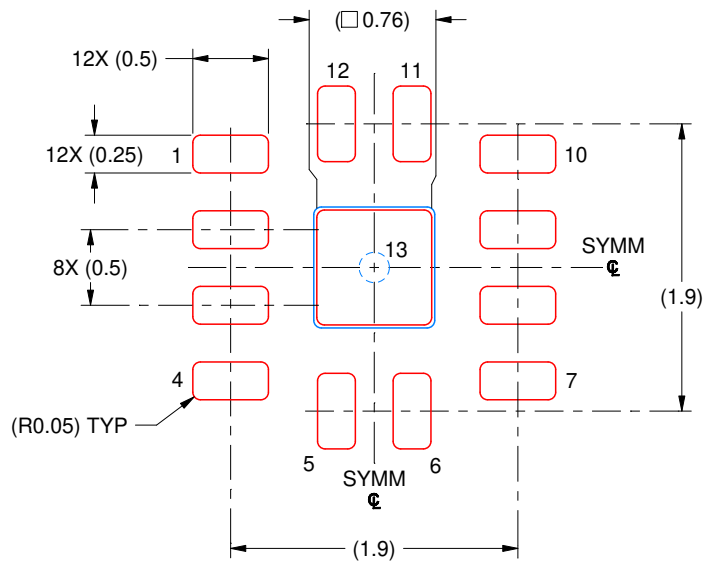
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RRL0012A

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 20X

EXPOSED PAD 13
90% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4224942/A 04/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025